

Green Products

Technical Data Data Sheet N0081, Rev. A

MBRF20100CTP SCHOTTKY RECTIFIER

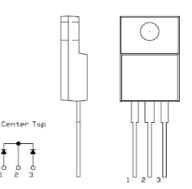
Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

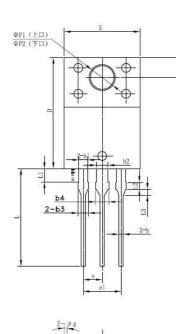
Features:

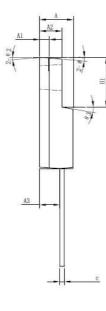
- 150 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

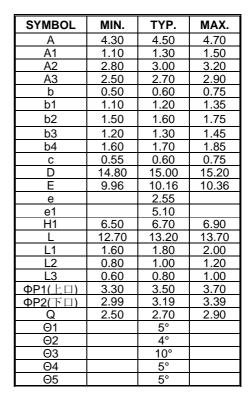




OUTLINE DRAWING





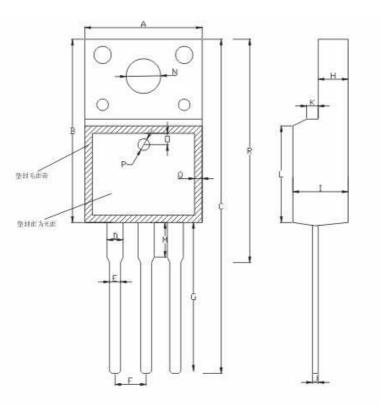


OPTION 1(HD)

Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 (86) 25-87123907 •
FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •



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A:10.20	± 0.50	B:15.90	±0.50	C:29.00	± 1.00	D:1.24	± 0.10
E:0.80	± 0.10	F:2.54	± 0.10	G:13.10	$^{\pm 1,0}$	H:2.55	± 0.05
I:4.70	± 0.05	J:0.50	± 0.05	K:1.20	± 0.20	L:8.00	± 0.50
M:3.00	± 0.50	N:3.20	± 0.20	O:1,25	± 0.05	P:1.5	± 0.05
Q:1.0	±0.20	R:19.2	± 1.0				

OPTION 2(SR)

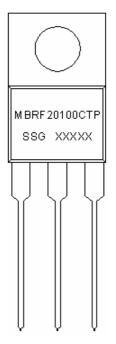
ITO-220AB



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Marking Diagram:



Where XXXXX is YYWWL

MBR F 20 100 CTP SSG YY WW	 Device Type Package type Forward Current (20A) Reverse Voltage (100V) Configuration SSG Year Week
WW	
L	= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
MBRF20100CTP	ITO-220AB (Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V _{RWM}	-	100	V
Max. Average Forward Current	I _{F(AV)}	50% duty cycle @T _C =105°C, rectangular wave form	20	А
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	150	А



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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V _{F1}	@ 10A, Pulse, T _J = 25 °C	0.90	V
(per leg) *	V _{F2}	@ 10A, Pulse, T _J = 125 °C	0.80	V
Max. Reverse Current at DC condition (per leg)	I _{R1}	$@V_R = rated V_R$ T _J = 25 °C	1.0	mA
Max. Reverse Current (per leg) *	I _{R2}	$@V_R = rated V_R$ T _J = 125 °C	6.0	mA
Max. Junction Capacitance (per leg)	C _T	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	250	pF
Typical Series Inductance (per leg)	Ls	Measured lead to lead 5 mm from package body	8.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/µs
RSM Isolation Voltage (t = 1.0 second, R. H. < =30%, $T_A = 25$ °C)	V _{ISO}	Clip mounting, the epoxy body away from the heatsink edge by more than 0.110" along the lead direction.	4500	V
		Clip mounting, the epoxy body is inside the heatsink.	3500	v
		Screw mounting, the epoxy body is inside the heatsink.	1500	

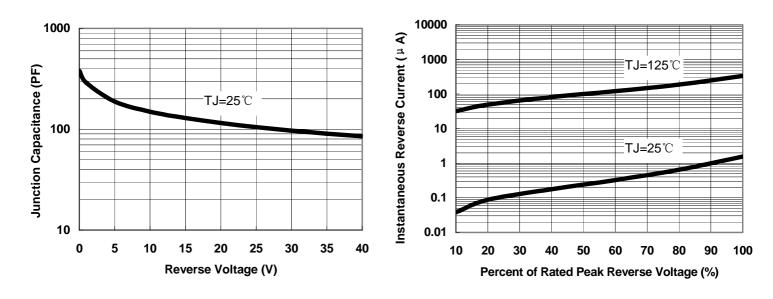
* Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	ΤJ	-	-55 to +150	°C
Max. Storage Temperature	T _{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case (per leg)	R _{θJC}	DC operation	3.5	°C/W
Approximate Weight	wt	-	2	g
Case Style		ITO-220AB		



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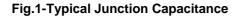


Fig.2-Typical Reverse Characteristics

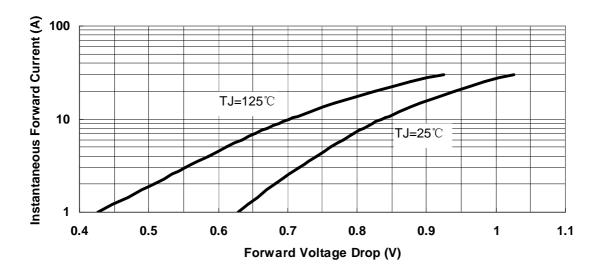


Fig.3-Typical Instantaneous Forward Voltage Characteristics



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